



UTG40N120WT

Preliminary

Insulated Gate Bipolar Transistor

1200V, SMPS N-CHANNEL IGBT

DESCRIPTION

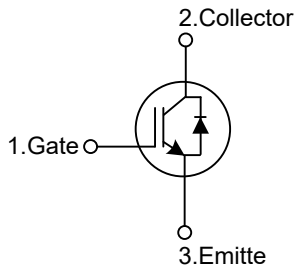
The UTC **UTG40N120WT** is a N-channel IGBT. it uses UTC's advanced technology to provide customers with high input impedance, high switching speed and low conduction loss, etc.

The UTC **UTG40N120WT** is suitable for high voltage switching, high frequency switch mode power supplies.

FEATURES

- * High switching speed
- * High avalanche ruggedness
- * Low saturation voltage: $V_{CE(SAT).Typ.} = 1.8V @ I_C=40A, V_{GE}=15V$ ($T_C = 25^{\circ}C$)

SYMBOL



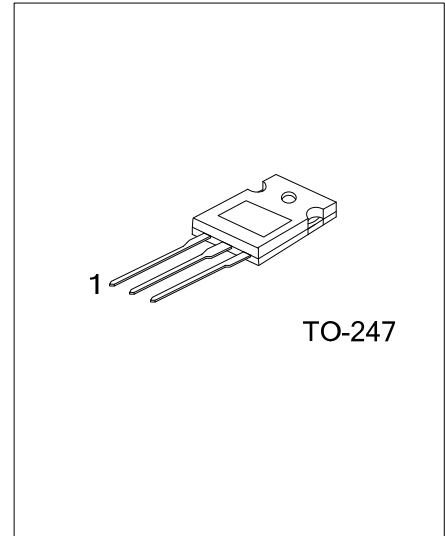
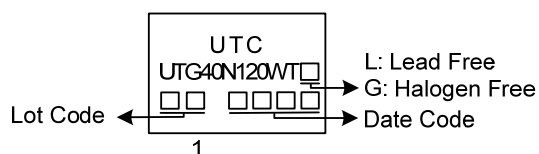
ORDERING INFORMATION

Ordering Number		Package	Pin Assignment			Packing
Lead Free	Halogen Free		1	2	3	
UTG40N120WTL-T47-T	UTG40N120WTG-T47-T	TO-247	G	C	E	Tube

Note: Pin Assignment: G: Gate C: Collector E: Emitter

UTG40N120WTG-T47-T		(1)Packing Type	(1) T: Tube
		(2)Package Type	(2) T47: TO-247
		(3)Green Package	(3) G: Halogen Free and Lead Free, L: Lead Free

MARKING



■ ABSOLUTE MAXIMUM RATINGS ($T_A=25^{\circ}\text{C}$, unless otherwise noted)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Emitter Voltage	V_{CES}	1200	V
Gate-Emitter Voltage	V_{GES}	± 20	V
Transient Gate-emitter voltage ($t_p < 5 \text{ ms}$)		± 25	V
Continuous Collector Current	I_C	$T_C=25^{\circ}\text{C}$	A
		$T_C=100^{\circ}\text{C}$	A
Collector Current Pulsed (Note 1)	I_{CM}	160	A
Diode Forward Current	I_F	$T_C=25^{\circ}\text{C}$	A
		$T_C=100^{\circ}\text{C}$	A
Short Circuit Withstand Time $V_{GE} = 15\text{V}$, $V_{CC} \leq 200\text{V}$ Allowed number of short circuits < 1000 Time between short circuits: $\geq 1.0\text{s}$ $T_{VJ} = 25^{\circ}\text{C}$	t_{SC}	5	μs
Power Dissipation ($T_C=25^{\circ}\text{C}$)	P_D	285	W
Operating Junction Temperature	T_J	$-40 \sim +150$	$^{\circ}\text{C}$
Storage Temperature Range	T_{STG}	$-55 \sim +150$	$^{\circ}\text{C}$

Notes: 1. Absolute maximum ratings are stress ratings only and functional device operation is not implied.
Absolute maximum ratings are those values beyond which the device could be permanently damaged.
2. Pulse width limited by maximum junction temperature.

■ THERMAL DATA

PARAMETER	SYMBOL	RATING	UNIT
Junction to Case	θ_{JC}	0.44	$^{\circ}\text{C/W}$

■ ELECTRICAL CHARACTERISTICS (T_C=25°C, unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS		MIN	TYP	MAX	UNIT
Off Characteristics							
Collector-Emitter Breakdown Voltage	BV _{CES}			1200			V
Collector Cut-Off Current	I _{CES}	V _{CE} =1200V, V _{GE} =0V				5	μA
G-E Leakage Current	I _{GES}	V _{CE} =0V, V _{GE} =±20V				±400	nA
On Characteristics							
Gate to Emitter Threshold Voltage	V _{GE(TH)}	I _C =250μA, V _{CE} =V _{GE}		4.5		7.5	V
Collector to Emitter Saturation Voltage	V _{CE(SAT)}	I _C =40A, V _{GE} =15V	T _C =25°C		1.8	2.3	V
			T _C =125°C		2.2		V
Dynamic Characteristics							
Input Capacitance	C _{IES}	V _{CE} =25V, V _{GE} =0V, f=1MHz			3490		pF
Output Capacitance	C _{OES}				129		pF
Reverse Transfer Capacitance	C _{RES}				32.5		pF
Switching Characteristics							
Total Gate Charge	Q _G	V _{CE} =600V, I _C =40A, V _{GE} =15V			152.4		nC
Gate-Emitter Charge	Q _{GE}				36.6		nC
Gate-Collector Charge	Q _{GC}				70.8		nC
Turn-On Delay Time	t _{DON}	V _{CC} =600V, I _C =40A, R _G =5Ω, V _{GE} =0~15V, L=500μH			20		ns
Rise Time	t _R				42.4		ns
Turn-Off Delay Time	t _{DOFF}				122		ns
Fall Time	t _F				254		ns
Turn-On Switching Loss	E _{ON}				3.186		mJ
Turn-Off Switching Loss	E _{OFF}				3.02		mJ
SOURCE- DRAIN DIODE RATINGS AND CHARACTERISTICS							
Forward Voltage Drop	V _F	I _F =40A				2.5	V
Reverse Recovery Time	t _{rr}	I _F =40A, dI/dt=100A/μS, V _{CC} =400V			68.2		ns
Reverse Recovery Charge	Q _{rr}				2.74		μC

■ TEST CIRCUIT AND WAVEFORMS

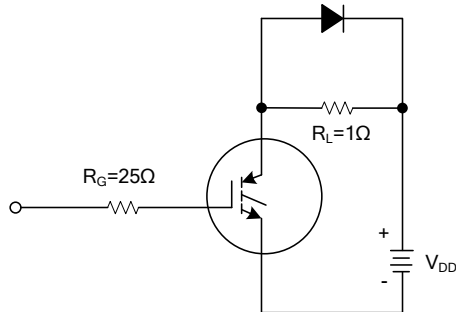


Fig 1. INDUCTIVE SWITCHING TEST CIRCUIT

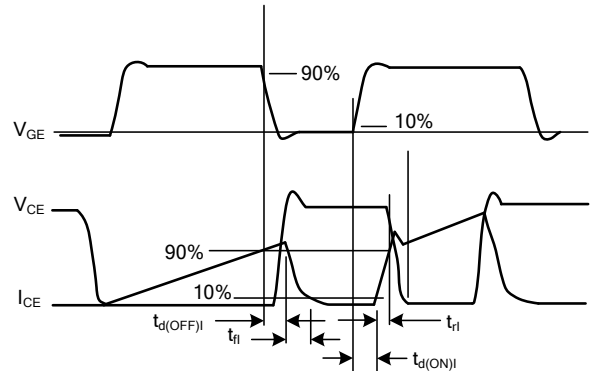


Fig 2. SWITCHING TEST WAVEFORMS

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